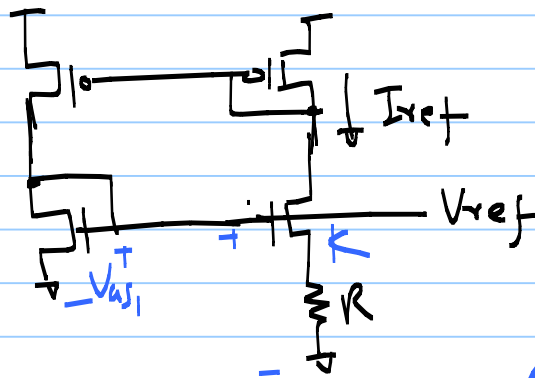


# ECE 5411 : Lecture 25.

Note Title

5/2/2011



$$I_{ref} = \frac{2}{\beta R_s^2} \left(1 - \frac{1}{\sqrt{K}}\right)^2$$

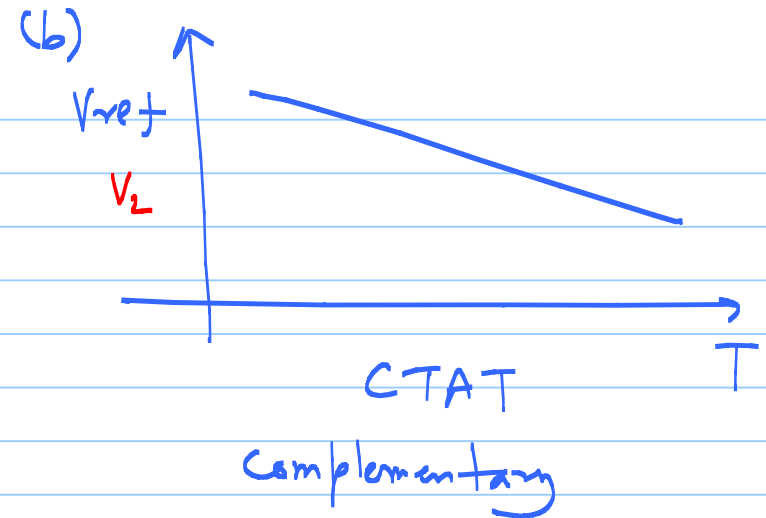
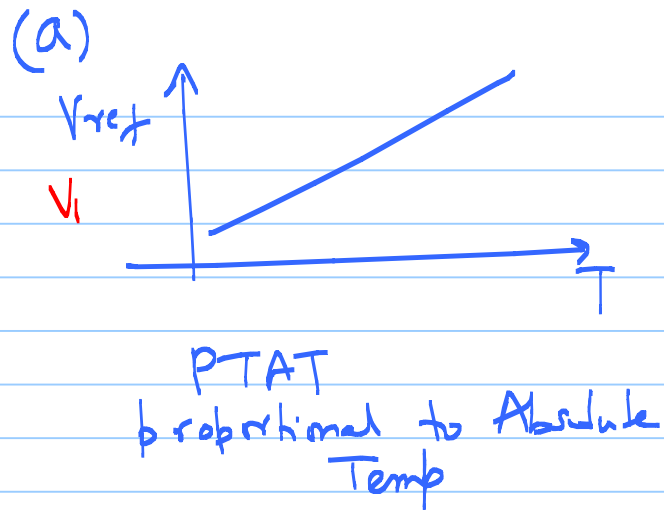
$$V_{ref} = \frac{2}{R_s \beta} \left(1 - \frac{1}{\sqrt{K}}\right) + V_{THN}$$

indep of  $V_{DD}$

$$\frac{\partial V_{ref}}{\partial T} = \left( \frac{\partial V_{THN}}{\partial T} \right) - \frac{2}{\beta R_s} \left(1 - \frac{1}{\sqrt{K}}\right) \left[ \frac{1}{R_s} \frac{dR}{dT} + \left( \frac{1}{K \mu_n} \frac{\partial K \mu_n}{\partial T} \right) \right] = 0 \quad ZTC$$

$$\frac{W}{L} \gg R_s \Rightarrow \frac{\partial V_{ref}}{\partial T} = 0$$

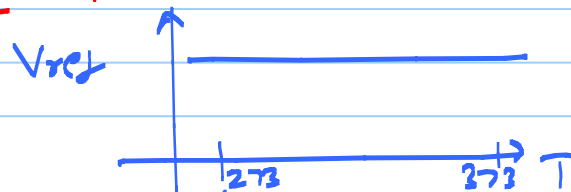
$-\frac{3/2}{T}$   
 Not practical



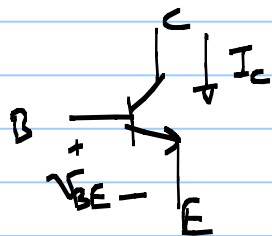
(c)  $V_{ref} = \alpha_1 V_1 + \alpha_2 V_2$

$$\frac{\partial V_{ref}}{\partial T} = \alpha_1 \frac{\partial V_1}{\partial T} + \alpha_2 \frac{\partial V_2}{\partial T} = 0$$

Zero temp Co  
(ZTC)



# ① CTAT (Negative TC reference)



Collector current

$$I_C = I_S e^{\frac{n V_{BE}}{V_T}} \approx I_S e^{\frac{V_{BE}}{V_T}}$$

$$\beta = \frac{I_C}{I_B} = \infty$$

$$n = 1$$

$$V_T \rightarrow \frac{kT}{q} = 26 \text{ mV}$$

$$\Rightarrow I_C = \underline{I_S} e^{\frac{V_{BE}}{V_T}}, \quad \text{①}$$

$$I_S \propto \mu k T n_i^2$$

$$n_i^2 \propto T^3 e^{-E_g/kT}$$

$$\mu \propto T^m$$

$$E_g = 1.12 \text{ eV for Si}$$

$$\Rightarrow \boxed{I_S = b T^{(4+m)} e^{-E_g/kT}} \quad \text{②}$$

from ①

$$\rightarrow V_{BE} = V_T \ln\left(\frac{I_C}{I_S}\right)$$

$$\underline{\underline{n=1}}$$

$$\underline{\underline{\frac{\partial V_{BE}}{\partial T}}} = \frac{\partial V_T}{\partial T} \ln\left(\frac{I_C}{I_S}\right) - \underbrace{\frac{V_T}{I_S} \left(\frac{\partial I_S}{\partial T}\right)}_{\text{}} \rightarrow \textcircled{3}$$

$$\times \quad \frac{\partial I_S}{\partial T} = \frac{(4+n)}{T} I_S + I_S \cdot \frac{E_g}{KT^2}$$

$$\times \quad \frac{V_T}{I_S} \frac{\partial I_S}{\partial T} = (4+n) \frac{V_T}{T} + \frac{E_g}{KT^2} \cdot V_T \rightarrow \textcircled{4}$$

from (3) & (4)

$$\frac{\partial V_{BE}}{\partial T} = \frac{V_T}{T} \ln\left(\frac{I_C}{I_S}\right) - (4+m) \frac{V_T}{T} - \frac{E_g}{kT^2} \cdot V_T$$

CTAT

⇒

$$\boxed{\frac{\partial V_{BE}}{\partial T} = \frac{V_{BE} - (4+m)V_T - E_g/q}{T}} \rightarrow (5)$$

TC of  $V_{BE}$  has a dependence on  $V_{BE}$  itself &  $T$

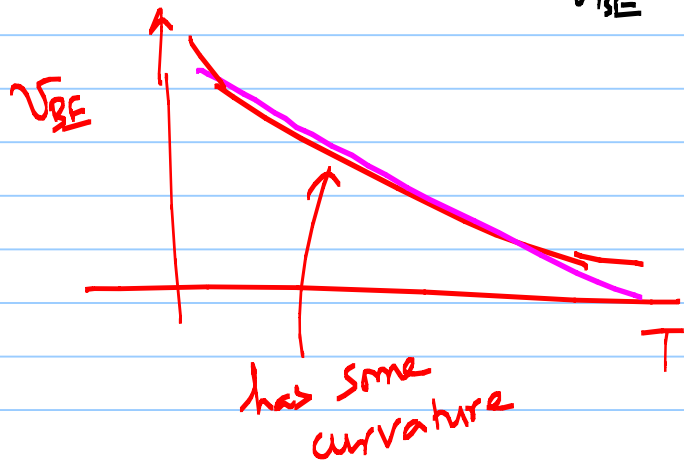
With  $V_{BE} = 0.75V$ ,  $T = 300K$

$$\frac{\partial V_{BE}}{\partial T} \approx -1.5 \frac{mV}{^{\circ}K}$$

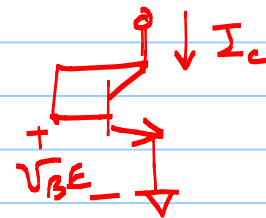
Since  $T \propto V_{BE} \rightarrow f(V_{BE}, T)$

↳ not a linear CTAT

↳ can't make a perfect ZTC reference

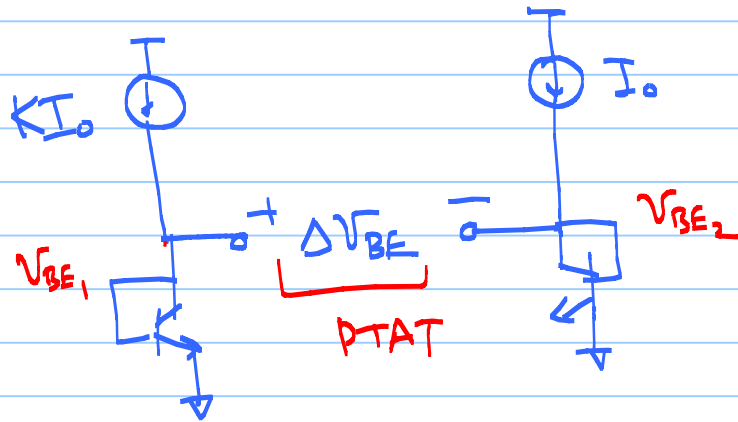


$V_{BE}$  itself is a CTAT.



## ② PTAT reference ( +ve TC )

Two BJT's operating at unequal currents



$$V_1 = V_T \ln(I_1)$$

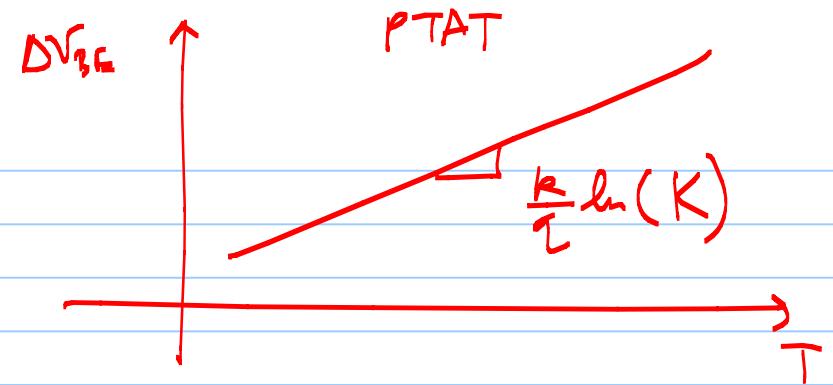
$$(V_1 - V_2) = V_T \ln\left(\frac{I_1}{I_2}\right)$$

$$V_T = \frac{kT}{q}$$

PTAT

$$\begin{aligned} \Delta V_{BE} &= V_{BE1} - V_{BE2} \\ &= V_T \ln\left(\frac{KI_0}{I_{S1}}\right) - V_T \ln\left(\frac{I_0}{I_{S2}}\right), \quad \text{for } I_{S1} = I_{S2} \\ &= V_T \ln(K) \end{aligned}$$

$$\Rightarrow \boxed{\frac{\partial \Delta V_{BE}}{\partial T} = \frac{k}{q} \ln(K)}$$



## Bandgap Reference :

Let's combine the CTAT & PTAT developed above.

$$V_{ref} = \alpha_1 \underbrace{V_{BE}}_{CTAT} + \alpha_2 \underbrace{(V_T \ln(K))}_{\substack{\Delta V_{BE12} \\ PTAT}}$$

$$TC_{V_{ref}} = 0 \Rightarrow \alpha_1 \frac{\partial V_{BE}}{\partial T} + \alpha_2 \left( \frac{k}{q} \ln(K) \right) = 0$$

$$\alpha_2 \ln(K) = \frac{-\alpha_1 \left( \frac{\partial V_{BE}}{\partial T} \right)}{(k/q)}$$

$\xrightarrow{\text{red arrow}} -1.5 \text{ mV/K}$   
 $\xrightarrow{\text{red arrow}} +0.087 \text{ mV/K}$

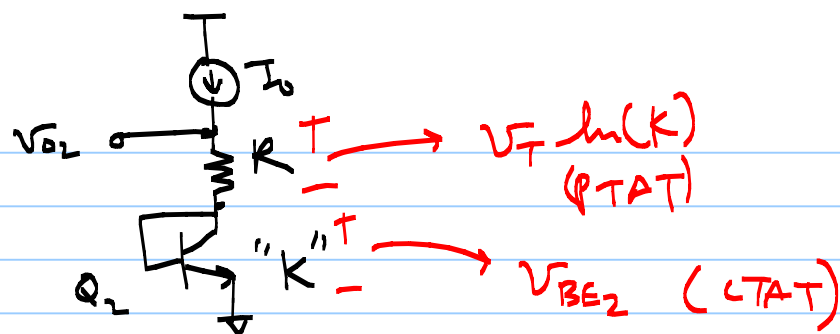
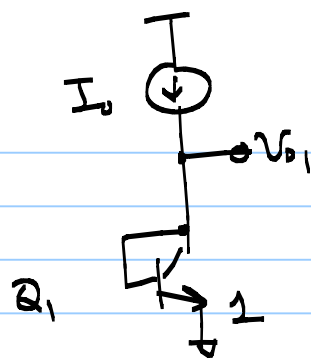
$$= \alpha_1 \times 17.2$$

Let  $\alpha_1 = 1 \Rightarrow$

$$\boxed{\alpha_2 \cdot \ln(K)} \Rightarrow 17.2$$

$$\Rightarrow V_{REF} = V_{BE} + 17.2 \times V_T$$

Curvature  
\* Curvature correction  
circuits



$$\beta \rightarrow \infty$$

For  $v_{o1} = v_{o2}$

$$\Rightarrow v_{BE1} = IR + v_{BE2}$$

$$\Rightarrow IR = v_{BE1} - v_{BE2}$$

$$= v_T \ln\left(\frac{I_0}{I_S}\right) - v_T \ln\left(\frac{I_0/K}{I_S}\right)$$

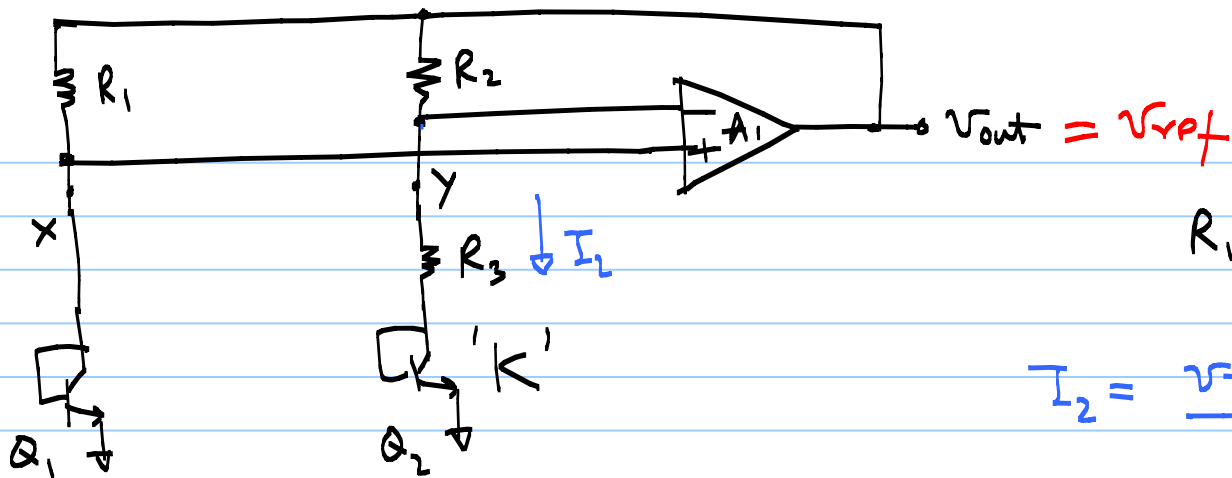
$$= v_T \ln(K)$$

$$V_{O2} = V_{BE2} + V_T \ln(K) \quad \leftarrow \text{can act like a ZTC reference}$$

$$\frac{\partial V_{O2}}{\partial T} = \frac{\partial V_{BE2}}{\partial T} + \left(\frac{k}{q}\right) \ln(K) \quad \alpha_1 = \alpha_2 = 1$$

$$\frac{1}{\alpha_2} \ln(K) = 17.2$$

$$K = e^{17.2} \quad \leftarrow \text{impractical!}$$



$$R_1 = R_2$$

$$I_2 = \frac{V_T \ln(K)}{R_3}$$

$$V_{out} = V_{BE2} + (R_2 + R_3) I_2$$

$$= \underbrace{1}_{\alpha_1} V_{BE2} + \underbrace{\left(1 + \frac{R_2}{R_3}\right)}_{\alpha_2} V_T \ln(K)$$

$$= V_{BE2} + 17.2 \cdot V_T$$

$$TC = 0$$

$$\left(1 + \frac{R_2}{R_3}\right) \ln(K) = 17.2$$

$$\Rightarrow K = 31 \text{ \& } \frac{R_2}{R_3} = 4$$

\* Why is it called BGR?

$$\alpha_1 = \alpha_2 = 1$$

$$V_{REF} = V_{BE} + V_T \ln(K)$$

$$\frac{\partial V_{REF}}{\partial T} = \frac{\partial V_{BE}}{\partial T} + \frac{V_T}{T} \ln(K) = 0 \quad \text{ZTC}$$

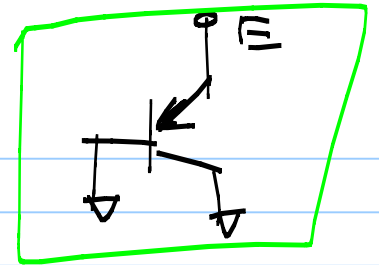
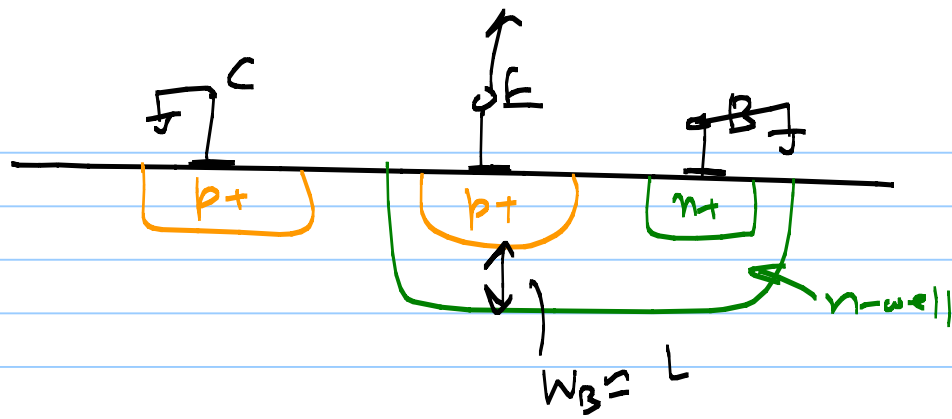
$$\rightarrow \frac{V_{BE} - (4+m)V_T - E_g/q}{T} = -\frac{V_T}{T} \ln(K)$$

$$\Rightarrow V_{REF} = \frac{E_g}{q} + (4+m)V_T \leftarrow$$

ZTC voltage  $\rightarrow \frac{E_g}{q}$  (Band gap voltage for Si)  $\approx 1.12 \text{ V}$   
 $\rightarrow m$  &  $V_T$

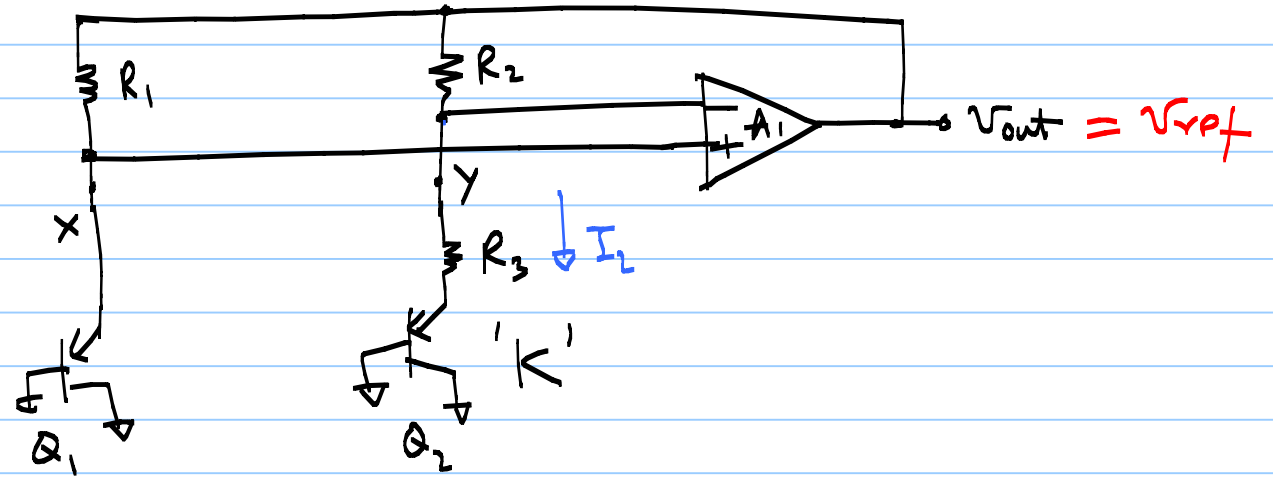
as  $T \rightarrow 0 \Rightarrow V_{ref} \rightarrow \frac{E_g}{2} \Rightarrow$   
"Bandgap Reference"

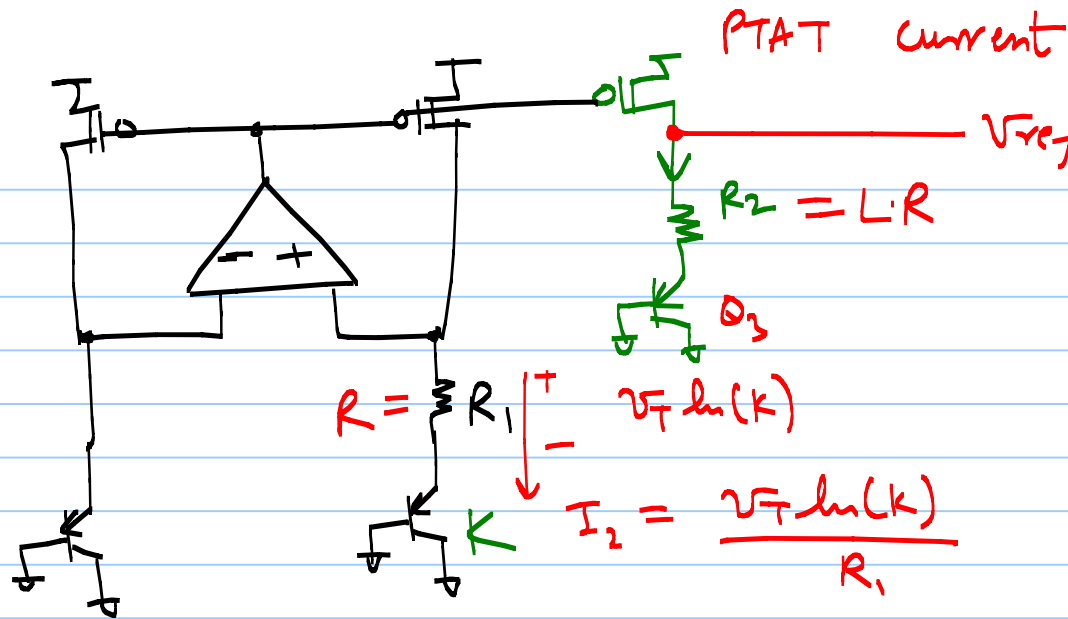
②



"Vertical  
PNP BJT"

$p$ -sub.





PTAT current

$$V_{ref} = V_{BE3} + V_T \ln K \cdot \left( \frac{R_2}{R_1} \right)$$

$$= V_{BE3} + V_T \cdot \underbrace{L \cdot \ln(K)}_{\Delta_2}$$

$$R_2 = L \cdot R$$

$Q_3$

$$R = R_1 \cdot V_T \ln(K)$$

$$I_2 = \frac{V_T \ln(K)}{R_1}$$

$$I_2 = \frac{V_T \ln(K)}{R_1} \quad R_1 \text{ is crossed out}$$

PTAT current